REVISIONS DATE **APPROVED** LTR DESCRIPTION Add device type 02, convert to 27 AUG. military drawing format, and inactivate for new design (device types O1AX and O1CX). Change code ident. no. to 67268. REV PAGE REV **REV STATUS OF PAGES PAGES** MILITARY DRAWING **Defense Electronics** This drawing is available for use by **Supply Center** all Departments and Agencies of the Dayton, Ohio Department of Defense TITLE: MICROCIRCUITS, DIGITAL, HIGH-SPEED CMOS, EXCLUSIVE NOR GATE, MONOLITHIC SILICON Original date of drawing: CODE IDENT. NO. 9 MAY 1984 DWG SIZE 84043 67268 Α REV OF AMSC N/A PAGE С 10 5962-E358

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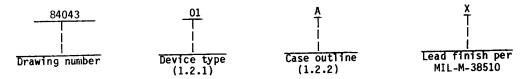
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1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of $\overline{\text{MIL}}$ -STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device types. The device types shall identify the circuit function as follows:

Device types	Generic number	Circuit function
01 02	54HC266 54HC7266	Quad 2-input exclusive NOR gate (open drain output) Quad 2-input exclusive NOR gate

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

outline letter	Case outline
A B C D	F-1 (14-lead, 1/4" x 1/4"), flat package fir 14 F-3 (14-lead, 3/16" x 1/4"), flat package Fir's D-1 (14-lead, 1/4" x 3/4"), dual-in-line package Of 19.7 F-2 (14-lead, 1/4" x 3/8"), flat package fir's C-2 (20-terminal, .350" x .350"), square chip carrier package

1.3 Absolute maximum ratings.

```
-0.5 V dc to +7.0 V dc
Supply voltage range 1/
                                           -0.5 V dc to V<sub>CC</sub> +0.5 V dc
-0.5 V dc to V<sub>CC</sub> +0.5 V dc
DC output voltage - - - - - - - - - - - - -
±20 mA
                                            ±25 mA
                                            ±50 mA
                                            -65°C to +150°C
Storage temperature range - - - - - - - -
                                            500 mW 2/
+260 C
Maximum power dissipation (Pp) - - - - - - Lead temperature (soldering, 10 seconds) - - -
See MIL-M-38510, appendix C
                                            60°C/W
+175°C
Junction temperature (Tj) ------
```

- 1/ Unless otherwise specified all voltages are referenced to ground.
- 2/ For $T_C = +100$ °C to +125°C, derate linearly at 12 mW/°C.
- 3/ When a thermal resistance for this case is listed in MIL-M-38510, appendix C, that value shall supersede the value indicated herein.

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1.4 Recommended operating conditions.

Supply voltage - - - - - - - - - - - - - - +2.0 V dc to +6.0 V dc Case operating temperature range - - - - - - - - - - - - - - -55°C to +125°C Input rise or fall time:

VCC = 2.0 V - - - - - - - - - - - - 0 to 1000 ns

VCC = 4.5 V - - - - - - - - - - - - 0 to 500 ns

VCC = 6.0 V - - - - - - - - - - - - 0 to 400 ns

2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 1.
 - 3.2.4 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

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Test	Symbol	-55°C < TC < 125°C, 1/			Conditions Device Group A -55°C < Tr < 125°C, 1/ type subgroups		Limits		Unit
<u> </u>		unless otherw	ified	+	1	Min	Max	V	
High-level output	Vон І	V _{IN} = V _{IH} or V _{IL} I _O <u><</u> 20 μA		V _{CC} = 2.0 V	02	1,2,3	1.9		, '
voltage	 			V _{CC} = 4.5 V	_		5.9	ļ	
	! !		. <u></u>	V _{CC} = 6.0 V	_			<u> </u>	1
	 	$ V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_0 \leq 4.0 \text{ mA}$		V _{CC} = 4.5 V		 	3.7	i !	İ İ
	 	VIN = VIH or VIL		V _{CC} = 6.0 V	_ 		5.2	 	
Low-level	I I V _{OL}	VIN = VIH or VIL		V _{CC} = 2.0 V	A11	1,2,3	i	0.1	 V
output voltage		Î <u><</u> 20 μΑ		VCC = 4.5 V	-			0.1	-į
		 VIN = VIH or VIL I ₀ < 4.0 mA		$V_{CC} = 6.0 \text{ V}$	- <u>i</u>		i	0.1	1
				V _{CC} = 4.5	- <u>i</u> !		1	0.4	<u> </u>
		VIN = VIH or VIL IO < 5.2 mA		V _{CC} = 6.0	-¦ 			0.4	1
High-level	† ∣ν _{ΙΗ}			V _{CC} = 2.0 V	A11	1,2,3	1.5	[٧
input voltage	1			V _{CC} = 4.5 V			3.15	 	-
<u>2</u> /	1			VCC = 6.0 V	_		4.2		j
Low-level	VIL			V _{CC} = 2.0 V	A11	1,2,3		0.3	V
input voltage		! 		$V_{CC} = 4.5 \text{ V}$	- <u> </u>	į	i	0.9	i I
<u>2</u> /				V _{CC} = 6.0 V	i	i !	i i	1.2	1
Input capacitance	 C _{in} 	$V_{in} = 0 V T_{C}$	= +25°C		A11	4	 	10	p
Quiescent current	Icc	ACC = 6.0 AII	N = ACC	or GND	All	1,2,3	<u> </u>	40	i u
Input leakaye current	IIN	V _{CC} = 6.0 V _{IN} = V _{CC} or GND				1,2,3	<u> </u>	i ±1	μ.
High-level output current	I _{IOH}	VI = VIH or VIL,		V _{CC} = 6 V	01	1,2,3	i ! 	i 10 i	μ
See footnotes a	at end o	f table.	SIZE	CODE IDENT	NO. DW	IG NO.			
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Test	Symbol	Condition -55°C < T _C <	ns	Device	Group A	Limi	its	Unit	
		-55°C < T _C < unless otherwise	125°C, <u>1</u> / specified	type	subgroups	Min	Max		
Functional test	 	 See 4.3.1d 		A11	7		 	<u> </u> 	
Propagation delay time,	ltpHL,	 T _C = +25°C C _L = 50 pF ±10%	V _{CC} = 2.0 V	A11	9		125	ns	
high-to-low,	PLH	-	V _{CC} = 4.5 V	- <u>į</u>	1		25	1	
low-to-high <u>3</u> /	 	See figure 3 	V _{CC} = 6.0 V	-	i i	<u> </u>	21	<u> </u>	
	<u> </u>	TC = -55°C +125°C C _L = 50 pF ±10%	V _{CC} = 2.0 V	A11	10,11		 190	l I n	
		C _L = 50 pF ±10%	V _{CC} = 4.5 V	- <u>i</u>	İ	į	38	ή	
	 	 See figure 3	V _{CC} = 6.0 V	-¦			32	<u> </u>	
Transition	tTHL,	T _C = +25°C	V _{CC} = 2.0 V	A11	9		75	l l n:	
time, high-to-low,	it _{tlh} I	C _L = 50 pF ±10%	$V_{CC} = 4.5 \text{ V}$	- <u> </u>	į		15	Ţ	
low-to-high 4/	 	See figure 3	$V_{CC} = 6.0 \text{ V}$	-¦	1	i	1 13	1	

 $I_{\rm CC}$ = 2.0 V

 $V_{CC} = 6.0 \text{ V}$

A11

10,11

110

22

19

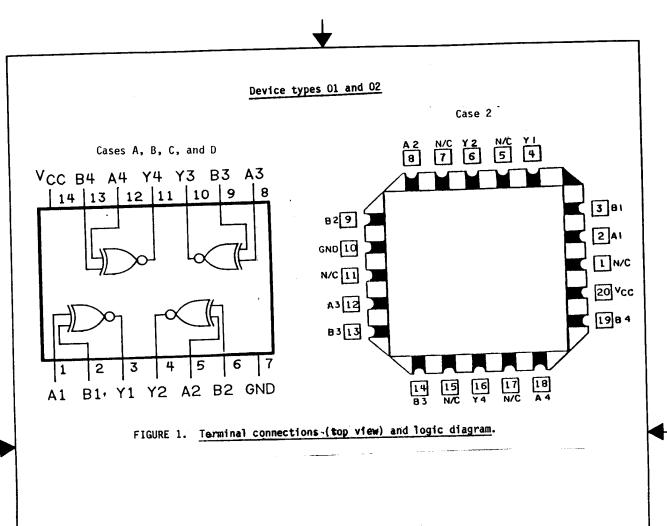
- For a power supply of 5 V ± 10 percent the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC}=5.5$ V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used. Power dissipation capacitance (I_{CD}), typically 25 pF, determines the no load dynamic power comsumption, I_{CC} and the no load dynamic current consumption, I_{CC} CC, and the no load dynamic current consumption, I_{CC} CC.
- $\underline{2}/$ Testing not required if applied as forcing function for v_{OH} or v_{OL} .

 $|C_L = 50 pF \pm 10\%$

|See figure 3

- 3/ AC testing at $\rm V_{CC}$ = 2.0 V and $\rm V_{CC}$ = 6.0 V shall be guaranteed, if not tested, to the specified parameters.
- 4/ Transition time (t_{THL} , t_{TLH}), if not tested, shall be guaranteed to the specified limits. Device type 01 T_{THL} only.

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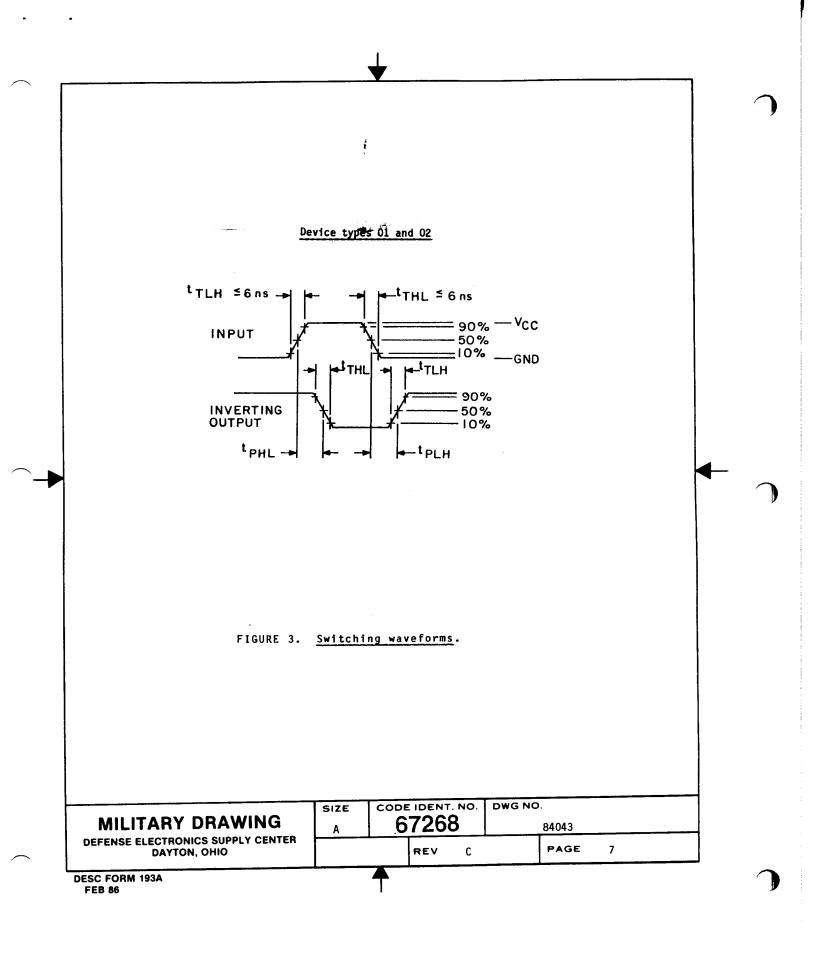


Device types 01 and 02

Inpu	ts	Outputs
A	В	ΓΥ
		Н .
L	Н	l L
Н	L	L
Н	Н	H H
	A A R	- AB + AB

FIGURE 2. Truth table.

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- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method $\overline{5005}$ of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 ($C_{\hbox{IN}}$ measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
 - d. Subgroup 7 tests sufficiently to verify the truth table.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.

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(3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004) 	
Final electrical test parameters (method 5004)	1*,2,3
Group A test requirements (method 5005)	1,2,3,4,7, 9,10,11**
Groups C and D end-point l electrical parameters l (method 5005)	
Additional electrical subgroups for group C periodic inspections	

- * PDA applies to subgroup 1.
- ** Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.
- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
 - 6.2 Replaceability. Replaceability is determined as follows:
 - a. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - b. When a QPL source is established, the part numbered device specified in this drawing will be replaced by the microcircuit identified as part number M38510/65103B-- and M38510/65105B--.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

	Military drawing part number	Vendor CAGE number	Yendor similar part number 1/	Replacement military specification part number
lise.	8404301AX 2/ NSC		 MM54HC266W/883B	M38510/651038AX
_	8404301BX	01295	SNJ54HC266WA	M38510/65103BBX
Disc.	 8404301CX 3/		I ISNJ54HC266J	M38510/65103BCX
	8404301DX ~		SNJ54HC266W	M38510/65103BDX
pisc.	84043012X /	01295	ISNJ54HC266FK	M38510/65103B2X
MOT	 8404302AX	27014	MM54HC7266W/883B	M38510/65105BAX
	8404302CX		 MM54HC7266J/883	M38510/65105BCX
	8404302CX	04713	54HC7266/BCAJC	M38510/65105BCX
_	8404302CX	18714	CD54HC7266F/3A	M38510/65105BCX
_	84043022X	04713	54HC7266M/B2CJC	M38510/65105B2X

1/ Caution: Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

2/ Inactive for new design. Not being manufactured, use military drawing part

number 8404302AX as a possible substitute.
3/ Inactive for new design. Use M38510/65103BCX.

Vendor CAGE number	Vendor name and address			
27014	National Semiconductor 2900 Semiconductor Drive Santa Clara, CA 95051			
01295	Texas Instruments, Incorporated P.O. Box 6448 Midland, TX 79701			
04713	Motorola, Incorporated 7402 S. Price Road Tempe, AZ 85283			
18714	RCA Corporation Solid State Division Route 202 Somerville, NJ 08876			

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